MC14028B

BCD-To-Decimal Decoder Binary-To-Octal Decoder

The MC14028B decoder is constructed so that an 8421 BCD code on the four inputs provides a decimal (one−of−ten) decoded output, while a 3−bit binary input provides a decoded octal (one−of−eight) code output with D forced to a logic “0”. Expanded decoding such as binary−to−hexadecimal (one−of−sixteen), etc., can be achieved by using other MC14028B devices. The part is useful for code conversion, address decoding, memory selection control, demultiplexing, or readout decoding.

Features

- Diode Protection on All Inputs
- Supply Voltage Range = 3.0 Vdc to 18 Vdc
- Capable of Driving Two Low−power TTL Loads or One Low−Power Schottky TTL Load Over the Rated Temperature Range
- Positive Logic Design
- Low Outputs on All Illegal Input Combinations
- Similar to CD4028B
- NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC−Q100 Qualified and PPAP Capable
- This Device is Pb−Free and is RoHS Compliant

MAXIMUM RATINGS (Voltages Referenced to V_{SS})

Parameter	Symbol	Value	Unit
DC Supply Voltage Range	V_{DD}	−0.5 to +18.0	V
Input or Output Voltage Range (DC or Transient)	V_{in}, V_{out}	−0.5 to V_{DD} + 0.5	V
Input or Output Current (DC or Transient) per Pin	I_{in}, I_{out}	±10	mA
Power Dissipation per Package (Note 1)	P_D	500	mW
Ambient Temperature Range	T_A	−55 to +125	°C
Storage Temperature Range	T_{stg}	−65 to +150	°C
Lead Temperature (8−Second Soldering)	T_L	260	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Temperature Derating: “D/DW” Packages: –7.0 mW/°C From 65°C To 125°C

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high−impedance circuit. For proper operation, V_{in} and V_{out} should be constrained to the range $V_{SS} \leq (V_{in}$ or $V_{out}) \leq V_{DD}$.

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either V_{SS} or V_{DD}). Unused outputs must be left open.

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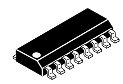
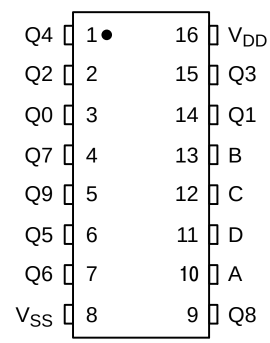
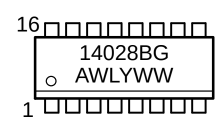


SOIC−16
D SUFFIX
CASE 751B

PIN ASSIGNMENT



MARKING DIAGRAM

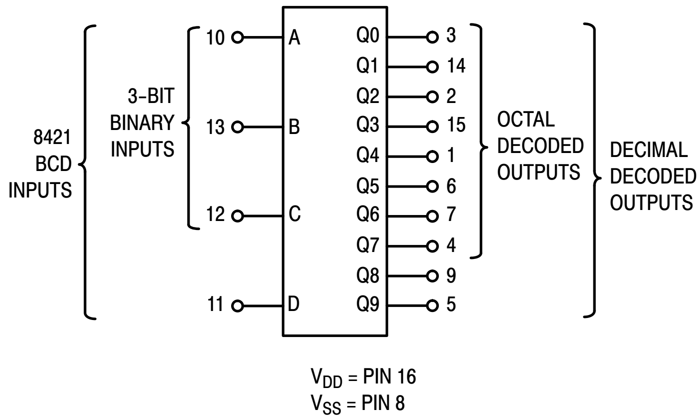


A	= Assembly Location
WL	= Wafer Lot
YY, Y	= Year
WW	= Work Week
G	= Pb−Free Package

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

BLOCK DIAGRAM



TRUTH TABLE

D	C	B	A	Q9	Q8	Q7	Q6	Q5	Q4	Q3	Q2	Q1	Q0
0	0	0	0	0	0	0	0	0	0	0	0	0	1
0	0	0	1	0	0	0	0	0	0	0	0	1	0
0	0	1	0	0	0	0	0	0	0	0	1	0	0
0	0	1	1	0	0	0	0	0	0	1	0	0	0
0	1	0	0	0	0	0	0	0	1	0	0	0	0
0	1	0	1	0	0	0	0	1	0	0	0	0	0
0	1	1	0	0	0	0	1	0	0	0	0	0	0
0	1	1	1	0	0	1	0	0	0	0	0	0	0
1	0	0	0	0	1	0	0	0	0	0	0	0	0
1	0	0	1	1	0	0	0	0	0	0	0	0	0
1	0	1	0	0	0	0	0	0	0	0	0	0	0
1	0	1	1	0	0	0	0	0	0	0	0	0	0
1	1	0	0	0	0	0	0	0	0	0	0	0	0
1	1	0	1	0	0	0	0	0	0	0	0	0	0
1	1	1	0	0	0	0	0	0	0	0	0	0	0
1	1	1	1	0	0	0	0	0	0	0	0	0	0

ORDERING INFORMATION

Device	Package	Shipping†
MC14028BDG	SOIC−16 (Pb−Free)	48 Units / Rail
MC14028BDR2G	SOIC−16 (Pb−Free)	2500 / Tape & Reel
NLV14028BDR2G*	SOIC−16 (Pb−Free)	2500 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.
*NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC−Q100 Qualified and PPAP Capable.

ELECTRICAL CHARACTERISTICS (Voltages Referenced to V_{SS})

Characteristic		Symbol	V_{DD} Vdc	−55°C Min	−55°C Max	25°C Min	25°C Typ (Note 2)	25°C Max	125°C Min	125°C Max	Unit
Output Voltage V_{in} = V_{DD} or 0	“0” Level	V_{OL}	5.0 10 15	– – –	0.05 0.05 0.05	– – –	0 0 0	0.05 0.05 0.05	– – –	0.05 0.05 0.05	Vdc
V_{in} = 0 or V_{DD}	“1” Level	V_{OH}	5.0 10 15	4.95 9.95 14.95	– – –	4.95 9.95 14.95	5.0 10 15	– – –	4.95 9.95 14.95	– – –	Vdc
Input Voltage (V_O = 4.5 or 0.5 Vdc) (V_O = 9.0 or 1.0 Vdc) (V_O = 13.5 or 1.5 Vdc)	“0” Level	V_{IL}	5.0 10 15	– – –	1.5 3.0 4.0	– – –	2.25 4.50 6.75	1.5 3.0 4.0	– – –	1.5 3.0 4.0	Vdc
(V_O = 0.5 or 4.5 Vdc) (V_O = 1.0 or 9.0 Vdc) (V_O = 1.5 or 13.5 Vdc)	“1” Level	V_{IH}	5.0 10 15	3.5 7.0 11	– – –	3.5 7.0 11	2.75 5.50 8.25	– – –	3.5 7.0 11	– – –	Vdc
Output Drive Current (V_{OH} = 2.5 Vdc) (V_{OH} = 4.6 Vdc) (V_{OH} = 9.5 Vdc) (V_{OH} = 13.5 Vdc)	Source	I_{OH}	5.0 5.0 10 15	–3.0 –0.64 –1.6 –4.2	– – – –	–2.4 –0.51 –1.3 –3.4	–4.2 –0.88 –2.25 –8.8	– – –	–1.7 –0.36 –0.9 –2.4	– – – –	mAdc
(V_{OL} = 0.4 Vdc) (V_{OL} = 0.5 Vdc) (V_{OL} = 1.5 Vdc)	Sink	I_{OL}	5.0 10 15	0.64 1.6 4.2	– – –	0.51 1.3 3.4	0.88 2.25 8.8	– – –	0.36 0.9 2.4	– – –	mAdc
Input Current		I_{in}	15	–	±0.1	–	±0.00001	±0.1	–	±1.0	μAdc
Input Capacitance (V_{in} = 0)		C_{in}	–	–	–	–	5.0	7.5	–	–	pF
Quiescent Current (Per Package)		I_{DD}	5.0 10 15	– – –	5.0 10 20	– – –	0.005 0.010 0.015	5.0 10 20	– – –	150 300 600	μAdc
Total Supply Current (Note 3, 4) (Dynamic plus Quiescent, Per Package) (C_L = 50 pF on all outputs, all buffers switching)		I_T	5.0 10 15	I_T = (0.3 μA/kHz) f + I_{DD} I_T = (0.6 μA/kHz) f + I_{DD} I_T = (0.9 μA/kHz) f + I_{DD}							μAdc

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

2. Data labelled “Typ” is not to be used for design purposes but is intended as an indication of the IC’s potential performance.
3. The formulas given are for the typical characteristics only at 25°C.
4. To calculate total supply current at loads other than 50 pF: $I_T(C_L) = I_T(50\ pF) + (C_L - 50)\ Vfk$ where: I_T is in μA (per package), C_L in pF, $V = (V_{DD} - V_{SS})$ in volts, f in kHz is input frequency, and k = 0.001.

SWITCHING CHARACTERISTICS (Note 5) (C_L = 50 pF, T_A = 25°C)

Characteristic	Symbol	V_{DD}	Min	Typ (Note 6)	Max	Unit
Output Rise and Fall Time t_{TLH}, t_{THL} = (1.5 ns/pF) C_L + 25 ns t_{TLH}, t_{THL} = (0.75 ns/pF) C_L + 12.5 ns t_{TLH}, t_{THL} = (0.55 ns/pF) C_L + 9.5 ns	t_{TLH}, t_{THL}	5.0 10 15	– – –	100 50 40	200 100 80	ns
Propagation Delay Time t_{PLH}, t_{PHL} = (1.7 ns/pF) C_L + 215 ns t_{PLH}, t_{PHL} = (0.66 ns/pF) C_L + 97 ns t_{PLH}, t_{PHL} = (0.5 ns/pF) C_L + 65 ns	t_{PLH}, t_{PHL}	5.0 10 15	– – –	300 130 90	600 260 180	ns

5. The formulas given are for the typical characteristics only at 25°C.
6. Data labelled “Typ” is not to be used for design purposes but is intended as an indication of the IC’s potential performance.

Inputs B, C, and D switching in respect to a BCD code.

All outputs connected to respective C_L loads. f in respect to a system clock.

Inputs A, B, and D low.

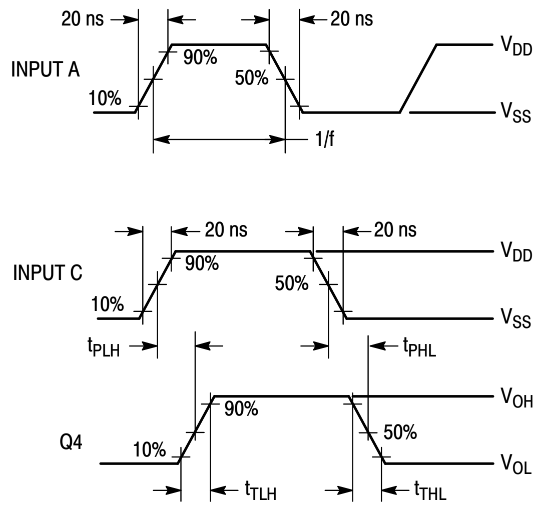
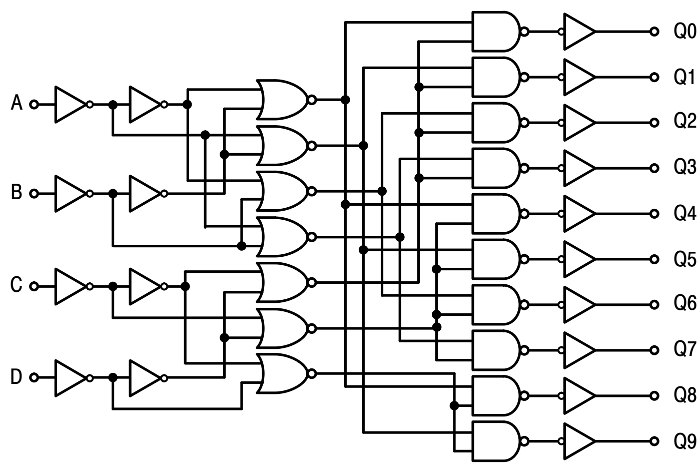


Figure 1. Dynamic Signal Waveforms



LOGIC DIAGRAM

APPLICATIONS INFORMATION

Expanded decoding can be performed by using the MC14028B and other CMOS Integrated Circuits. The circuit in Figure 2 converts any 4−bit code to a decimal or hexadecimal code. The accompanying table shows the input binary combinations, the associated “output numbers” that go “high” when selected, and the “redefined output numbers” needed for the proper code. For example: For the combination DCBA = 0111 the output number 7 is redefined for the 4−bit binary, 4−bit gray, excess−3, or excess−3 gray codes as 7, 5, 4, or 2, respectively. Figure 3 shows a 6−bit binary 1−of−64 decoder using nine MC14028B circuits and two MC14069UB inverters.

The MC14028B can be used in decimal digit displays, such as, neon readouts or incandescent projection indicators as shown in Figure 4.

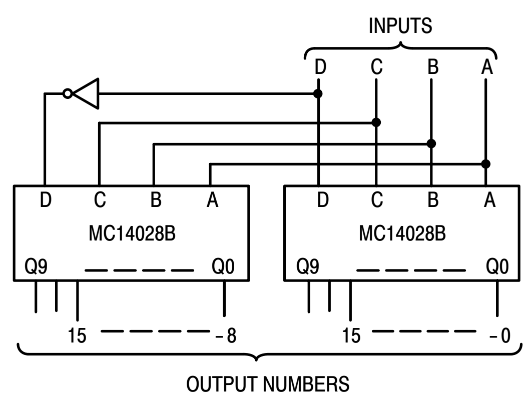


Figure 2. Code Conversion Circuit and Truth Table

Inputs				Output Numbers																Code and Redefined Output Numbers					
																				Hexadecimal			Decimal		
D	C	B	A	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0	4−Bit Binary	4−Bit Gray	Excess−3	Excess−3 Gray	Aiken	4221
0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	1	0	0			0	0
0	0	0	1	0	0	0	0	0	0	0	0	0	0	0	0	0	0	1	0	1	1			1	1
0	0	1	0	0	0	0	0	0	0	0	0	0	0	0	0	0	1	0	0	2	3		0	2	2
0	0	1	1	0	0	0	0	0	0	0	0	0	0	0	0	1	0	0	0	3	2	0	3	3	
0	1	0	0	0	0	0	0	0	0	0	0	0	0	0	1	0	0	0	0	4	7	1	4	4	
0	1	0	1	0	0	0	0	0	0	0	0	0	0	1	0	0	0	0	0	5	6	2			3
0	1	1	0	0	0	0	0	0	0	0	0	0	1	0	0	0	0	0	0	6	4	3	1		4
0	1	1	1	0	0	0	0	0	0	0	0	1	0	0	0	0	0	0	0	7	5	4	2		
1	0	0	0	0	0	0	0	0	0	0	1	0	0	0	0	0	0	0	0	8	15	5			
1	0	0	1	0	0	0	0	0	0	1	0	0	0	0	0	0	0	0	0	9	14	6			5
1	0	1	0	0	0	0	0	0	1	0	0	0	0	0	0	0	0	0	0	10	12	7	9		6
1	0	1	1	0	0	0	0	1	0	0	0	0	0	0	0	0	0	0	0	11	13	8		5	
1	1	0	0	0	0	0	1	0	0	0	0	0	0	0	0	0	0	0	0	12	8	9	5	6	
1	1	0	1	0	0	1	0	0	0	0	0	0	0	0	0	0	0	0	0	13	9		6	7	7
1	1	1	0	0	1	0	0	0	0	0	0	0	0	0	0	0	0	0	0	14	11		8	8	8
1	1	1	1	1	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	15	10		7	9	9

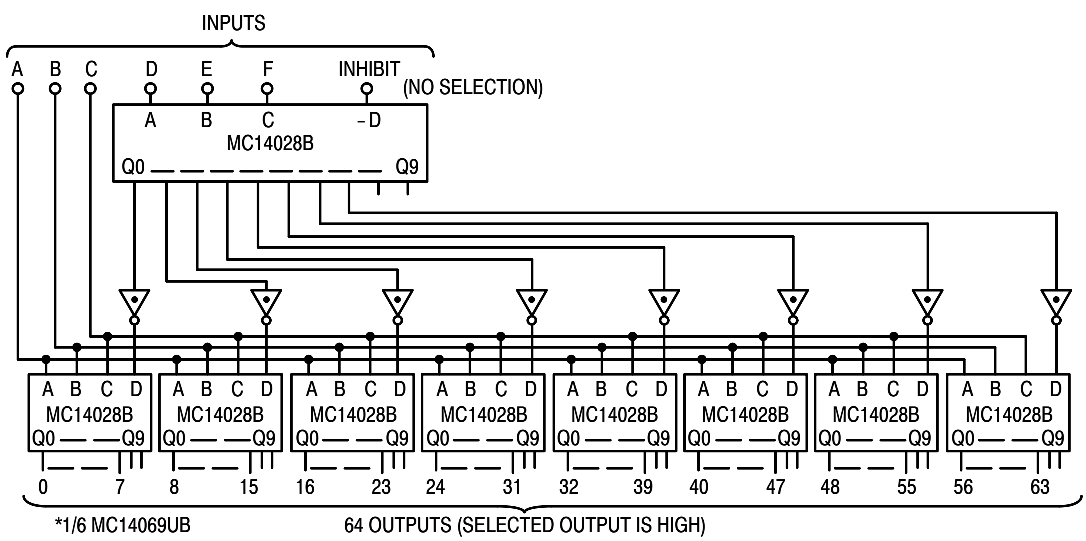


Figure 3. Six−Bit Binary 1−of−64 Decoder

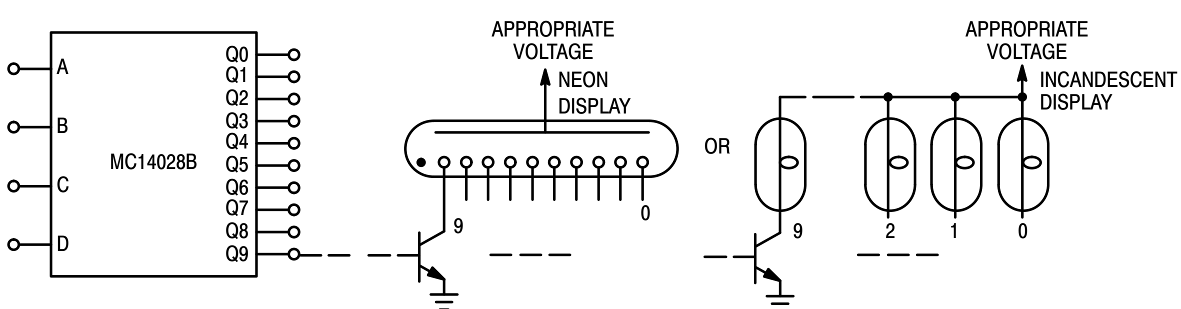
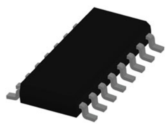


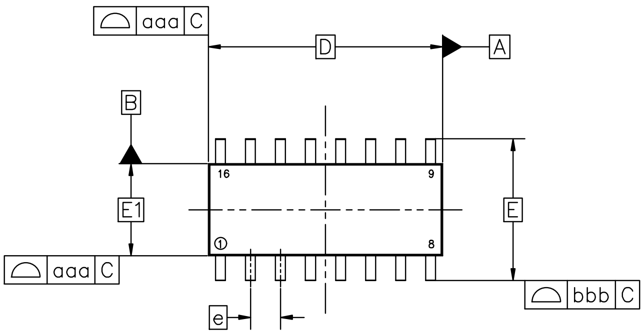
Figure 4. Decimal Digit Display Application



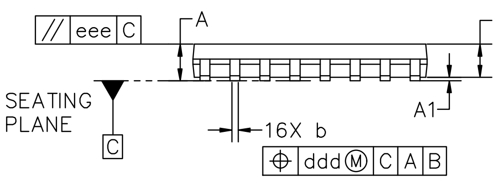
SOIC−16 9.90x3.90x1.37 1.27P
CASE 751B
ISSUE M

DATE 18 OCT 2024

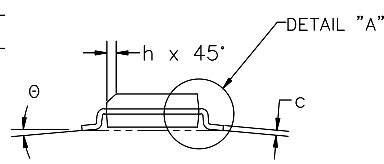
NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018.
2. DIMENSION IN MILLIMETERS. ANGLE IN DEGREES.
3. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15mm PER SIDE.
5. DIMENSION b DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127mm TOTAL IN EXCESS OF THE b DIMENSION AT MAXIMUM MATERIAL CONDITION.



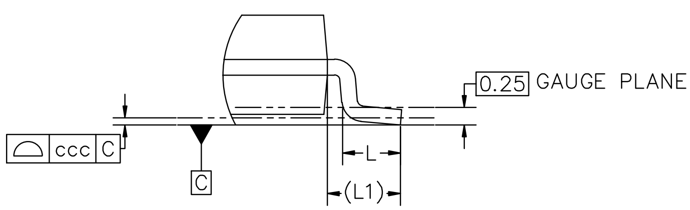
TOP VIEW



SIDE VIEW

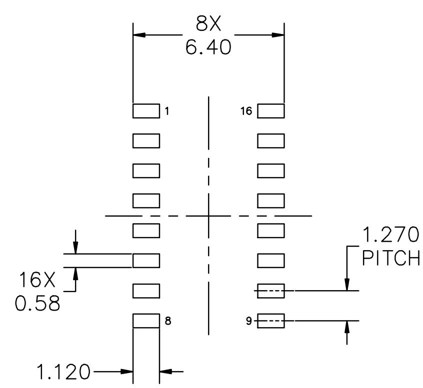


END VIEW



DETAIL "A"
Scale 3:1

MILLIMETERS			
DIM	MIN	NOM	MAX
A	1.35	1.55	1.75
A1	0.10	0.18	0.25
A2	1.25	1.37	1.50
b	0.35	0.42	0.49
c	0.19	0.22	0.25
D	9.90 BSC		
E	6.00 BSC		
E1	3.90 BSC		
e	1.27 BSC		
h	0.25	−−−	0.50
L	0.40	0.83	1.25
L1	1.05 REF		
Θ	0°	−−−	7°
TOLERANCE OF FORM AND POSITION			
aaa	0.10		
bbb	0.20		
ccc	0.10		
ddd	0.25		
eee	0.10		



RECOMMENDED MOUNTING FOOTPRINT

*FOR ADDITIONAL INFORMATION ON OUR PB−FREE STRATEGY AND SOLDERING DETAILS, PLEASE DOWNLOAD THE onsemi SOLDERING AND MOUNTING TECHNIQUES REFERENCE MANUAL, SOLDERRM/D

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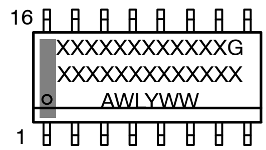
SOIC−16 9.90x3.90x1.37 1.27P
CASE 751B
ISSUE M

DATE 18 OCT 2024

GENERIC MARKING DIAGRAM*



XXXXX = Specific Device Code
A = Assembly Location
WL = Wafer Lot
Y = Year
WW = Work Week
G = Pb−Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb−Free indicator, “G” or microdot “▪”, may or may not be present. Some products may not follow the Generic Marking.

PIN	STYLE 1:	STYLE 2:	STYLE 3:	STYLE 4:
PIN 1.	COLLECTOR	CATHODE	COLLECTOR, DYE #1	COLLECTOR, DYE #1
2.	BASE	ANODE	BASE, #1	COLLECTOR, #1
3.	EMITTER	NO CONNECTION	EMITTER, #1	COLLECTOR, #2
4.	NO CONNECTION	CATHODE	COLLECTOR, #1	COLLECTOR, #2
5.	EMITTER	CATHODE	COLLECTOR, #2	COLLECTOR, #3
6.	BASE	NO CONNECTION	BASE, #2	COLLECTOR, #3
7.	COLLECTOR	ANODE	EMITTER, #2	COLLECTOR, #4
8.	COLLECTOR	CATHODE	COLLECTOR, #2	COLLECTOR, #4
9.	BASE	CATHODE	COLLECTOR, #3	BASE, #4
10.	EMITTER	ANODE	BASE, #3	EMITTER, #4
11.	NO CONNECTION	NO CONNECTION	EMITTER, #3	BASE, #3
12.	EMITTER	CATHODE	COLLECTOR, #3	EMITTER, #3
13.	BASE	CATHODE	COLLECTOR, #4	BASE, #2
14.	COLLECTOR	NO CONNECTION	BASE, #4	EMITTER, #2
15.	EMITTER	ANODE	EMITTER, #4	BASE, #1
16.	COLLECTOR	CATHODE	COLLECTOR, #4	EMITTER, #1

PIN	STYLE 5:	STYLE 6:	STYLE 7:
PIN 1.	DRAIN, DYE #1	CATHODE	SOURCE N-CH
2.	DRAIN, #1	CATHODE	COMMON DRAIN (OUTPUT)
3.	DRAIN, #2	CATHODE	COMMON DRAIN (OUTPUT)
4.	DRAIN, #2	CATHODE	GATE P-CH
5.	DRAIN, #3	CATHODE	COMMON DRAIN (OUTPUT)
6.	DRAIN, #3	CATHODE	COMMON DRAIN (OUTPUT)
7.	DRAIN, #4	CATHODE	COMMON DRAIN (OUTPUT)
8.	DRAIN, #4	CATHODE	SOURCE P-CH
9.	GATE, #4	ANODE	SOURCE P-CH
10.	SOURCE, #4	ANODE	COMMON DRAIN (OUTPUT)
11.	GATE, #3	ANODE	COMMON DRAIN (OUTPUT)
12.	SOURCE, #3	ANODE	COMMON DRAIN (OUTPUT)
13.	GATE, #2	ANODE	GATE N-CH
14.	SOURCE, #2	ANODE	COMMON DRAIN (OUTPUT)
15.	GATE, #1	ANODE	COMMON DRAIN (OUTPUT)
16.	SOURCE, #1	ANODE	SOURCE N-CH

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